

# 1MBI75U4F-120L-50

IGBT Modules

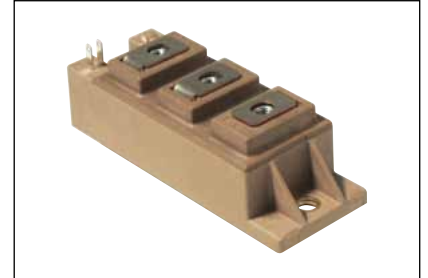
## IGBT MODULE (U series) 1200V / 75A / 1 in one package

### ■ Features

- High speed switching
- Voltage drive
- Low Inductance module structure

### ■ Applications

- Inverter DB for Motor Drive
- AC and DC Servo Drive Amplifier (DB)
- Active PFC
- Industrial machines



### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items	Symbols	Conditions	Maximum ratings	Units	
Collector-Emitter voltage	V <sub>CES</sub>		1200	V	
Gate-Emitter voltage	V <sub>GES</sub>		±20	V	
Collector current	I <sub>c</sub>	Continuous	Tc=25°C	100	A
			Tc=80°C	75	
	I <sub>cp</sub>	1ms	Tc=25°C	200	
			Tc=80°C	150	
	-I <sub>c</sub>			35	
-I <sub>c</sub> pulse	1ms		70		
Collector power dissipation	P <sub>c</sub>	1 device	400	W	
Reverse voltage for FWD	V <sub>R</sub>		1200	V	
Forward current for FWD	I <sub>F</sub>	Continuous	100	A	
	I <sub>F</sub> pulse	1ms	200		
Junction temperature	T <sub>j</sub>		+150	°C	
Storage temperature	T <sub>stg</sub>		-40~+125	°C	
Isolation voltage	Between terminal and copper base (*1) V <sub>iso</sub>	AC : 1min.	2500	VAC	
Screw torque	Mounting (*2)		3.5	Nm	
	Terminals (*3)				

Note \*1: All terminals should be connected together when isolation test will be done.

Note \*2: Recommendable Value : 2.5 to 3.5 Nm (M5 or M6)

Note \*3: Recommendable Value : 2.5 to 3.5 Nm (M5)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero gate voltage collector current	I <sub>CES</sub>	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 1200V	-	-	1.0	mA	
Gate-Emitter leakage current	I <sub>GES</sub>	V <sub>CE</sub> = 0V, V <sub>GE</sub> = ±20V	-	-	200	nA	
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	V <sub>CE</sub> = 20V, I <sub>c</sub> = 75mA	4.5	6.5	8.5	V	
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub> (terminal)	V <sub>GE</sub> = 15V I <sub>c</sub> = 75A	Tj=25°C	-	2.05	2.20	V
			Tj=125°C	-	2.25	-	
	V <sub>CE(sat)</sub> (chip)		Tj=25°C	-	1.90	2.05	
			Tj=125°C	-	2.10	-	
Input capacitance	Cies	V <sub>GE</sub> = 0V, V <sub>CE</sub> = 10V, f = 1MHz	-	8	-	nF	
Turn-on time	ton	V <sub>CC</sub> = 600V, I <sub>c</sub> = 75A V <sub>GE</sub> = ±15V, R <sub>G</sub> = 9.1Ω	-	0.32	1.20	μs	
	tr		-	0.10	0.60		
	tr(i)		-	0.03	-		
Turn-off time	toff		-	0.41	1.00		
	tf		-	0.07	0.30		
Forward on voltage	V <sub>F</sub> (terminal)	V <sub>GE</sub> = 0V I <sub>F</sub> = 35A	Tj=25°C	-	1.65	2.00	V
			Tj=125°C	-	1.75	-	
	V <sub>F</sub> (chip)		Tj=25°C	-	1.60	1.85	
			Tj=125°C	-	1.70	-	
Reverse Current	IR	V <sub>CE</sub> = 1200V	-	-	1.0	mA	
Forward on voltage	V <sub>F</sub> (terminal)	V <sub>GE</sub> = 0V I <sub>F</sub> = 100A	Tj=25°C	-	1.75	1.90	V
			Tj=125°C	-	1.90	-	
	V <sub>F</sub> (chip)		Tj=25°C	-	1.60	1.75	
			Tj=125°C	-	1.75	-	
Reverse recovery time	trr	I <sub>F</sub> = 100A	-	-	0.35	μs	
Lead resistance, terminal-chip(*4)	R lead		-	1.39	-	mΩ	

Note \*4: Biggest internal terminal resistance among arm.

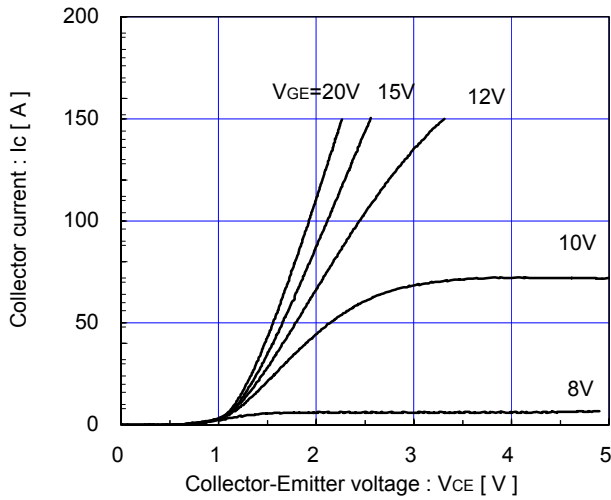
● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance (1device)	Rth(j-c)	IGBT	-	-	0.31	°C/W
		Inverse Diode	-	-	0.88	
		FWD	-	-	0.40	
Contact thermal resistance	Rth(c-f)	with Thermal Compound (*5)	-	0.05	-	

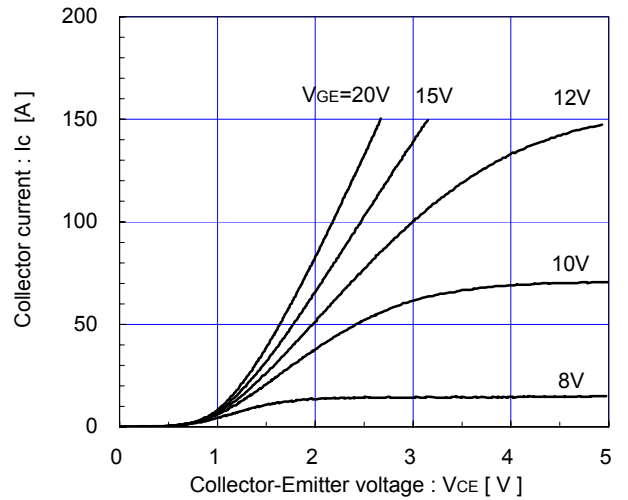
Note \*5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

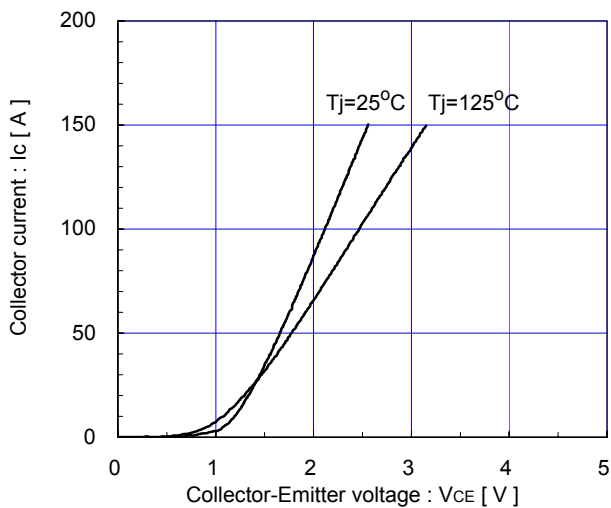
Collector current vs. Collector-Emitter voltage (typ.)  
T<sub>j</sub>=25°C / chip



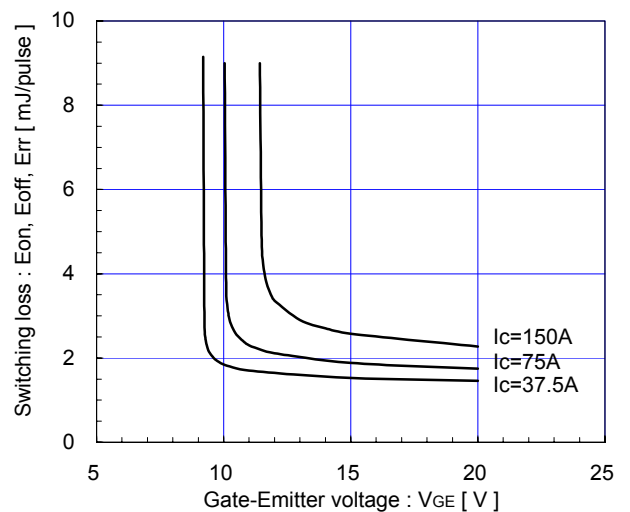
Collector current vs. Collector-Emitter voltage (typ.)  
T<sub>j</sub>=125°C / chip



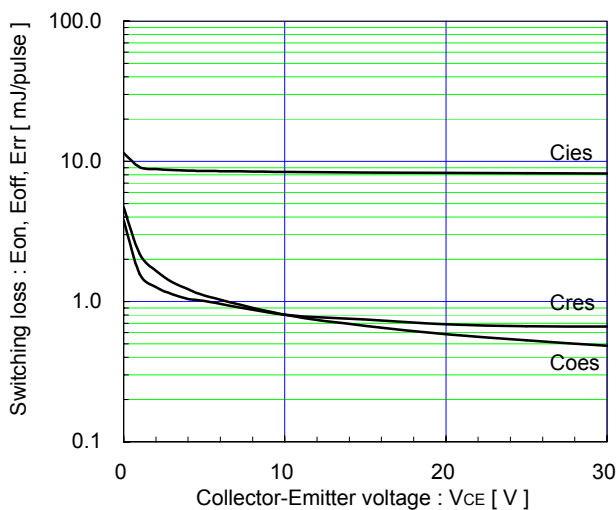
Collector current vs. Collector-Emitter voltage (typ.)  
V<sub>GE</sub>=15V / chip



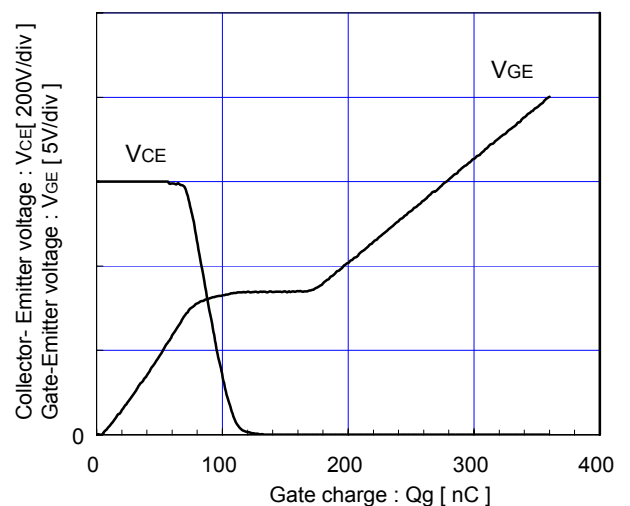
Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)  
T<sub>j</sub>=25°C / chip



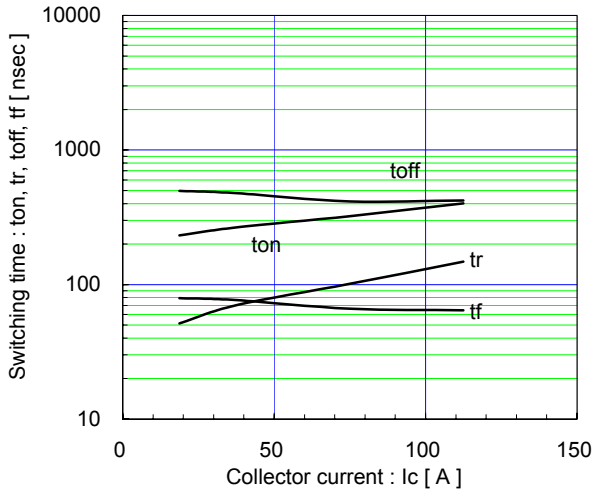
Capacitance vs. Collector-Emitter voltage (typ.)  
V<sub>GE</sub>=0V, f=1MHz, T<sub>j</sub>=25°C



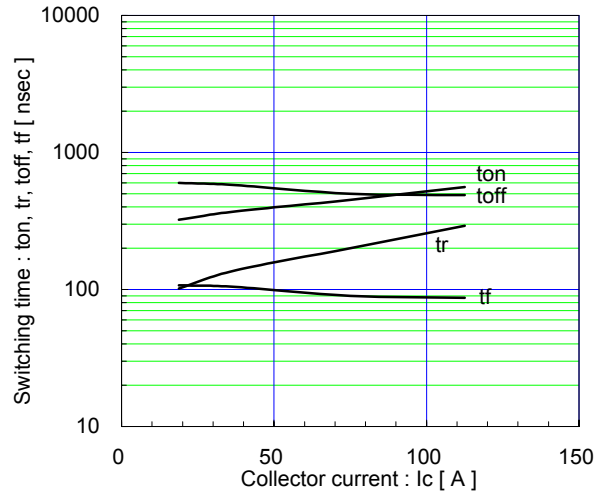
Dynamic Gate charge (typ.)  
V<sub>cc</sub>=600V, I<sub>c</sub>=75A, T<sub>j</sub>=25°C



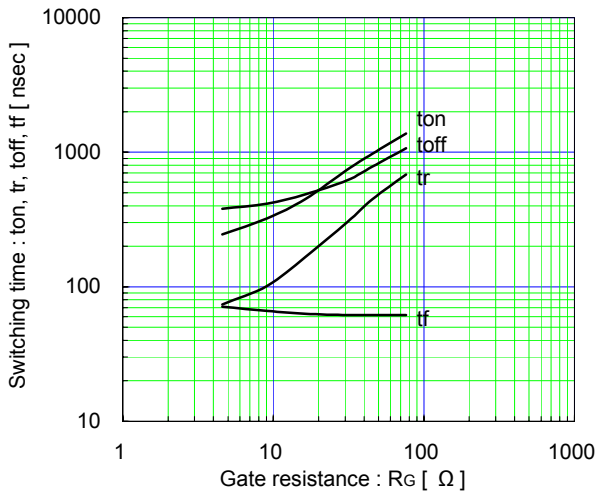
Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=9.1\Omega, T_j=25^\circ C$



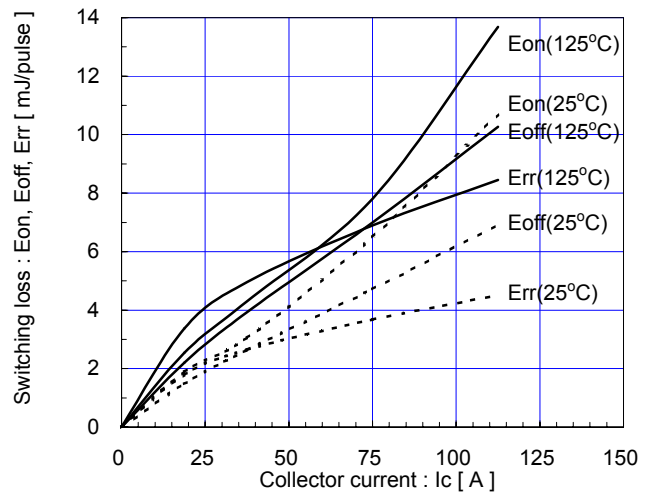
Switching time vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=9.1\Omega, T_j=125^\circ C$



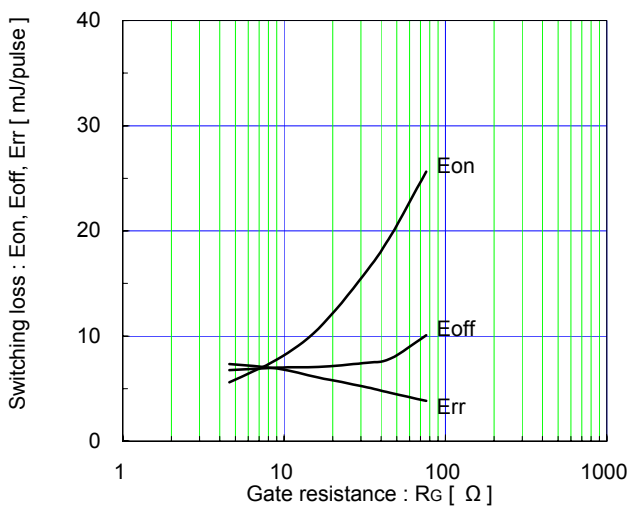
Switching time vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_c=75A, V_{GE}=\pm 15V, T_j=25^\circ C$



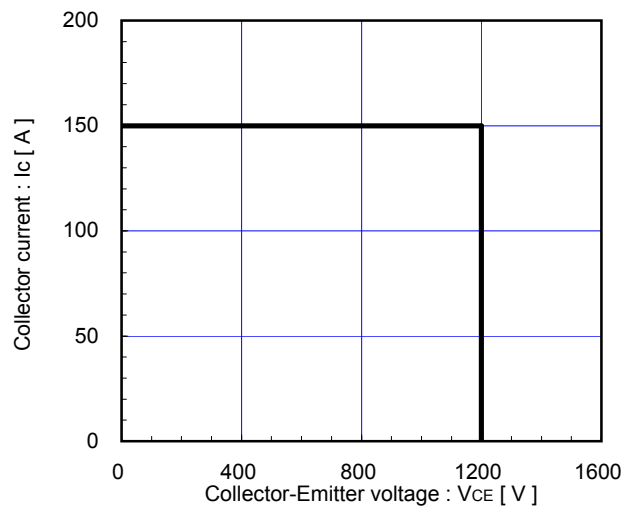
Switching loss vs. Collector current (typ.)  
 $V_{CC}=600V, V_{GE}=\pm 15V, R_G=9.1\Omega$

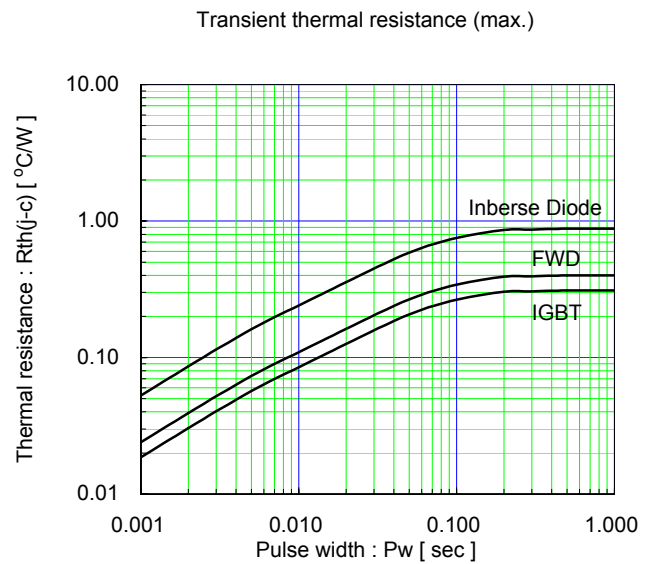
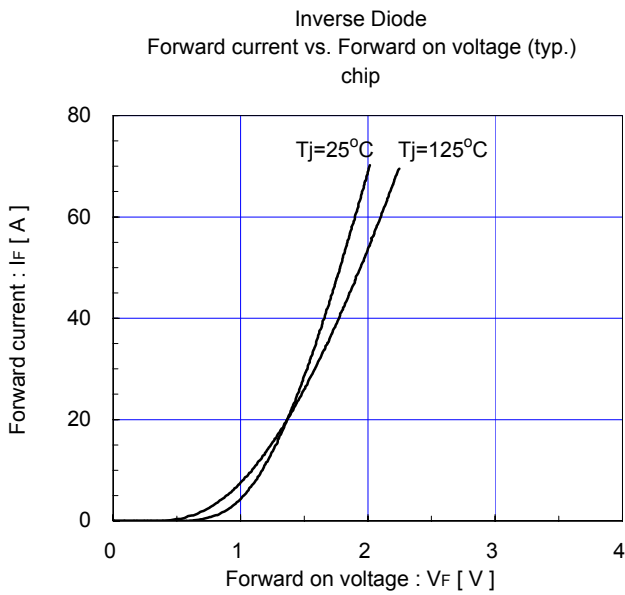
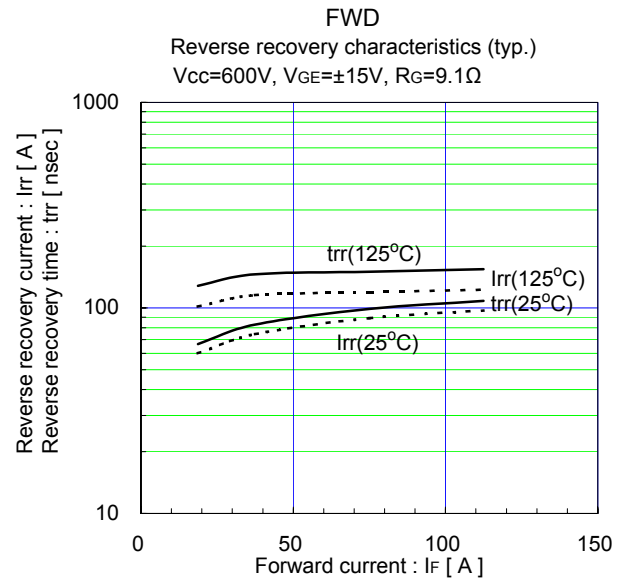
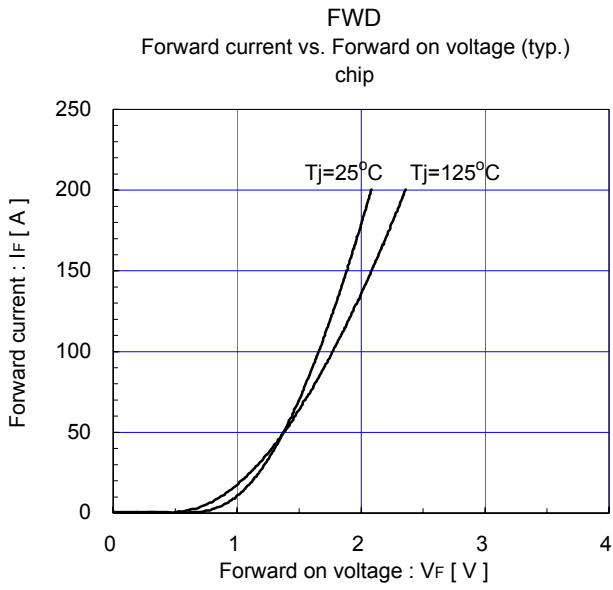


Switching loss vs. Gate resistance (typ.)  
 $V_{CC}=600V, I_c=75A, V_{GE}=\pm 15V, T_j=125^\circ C$

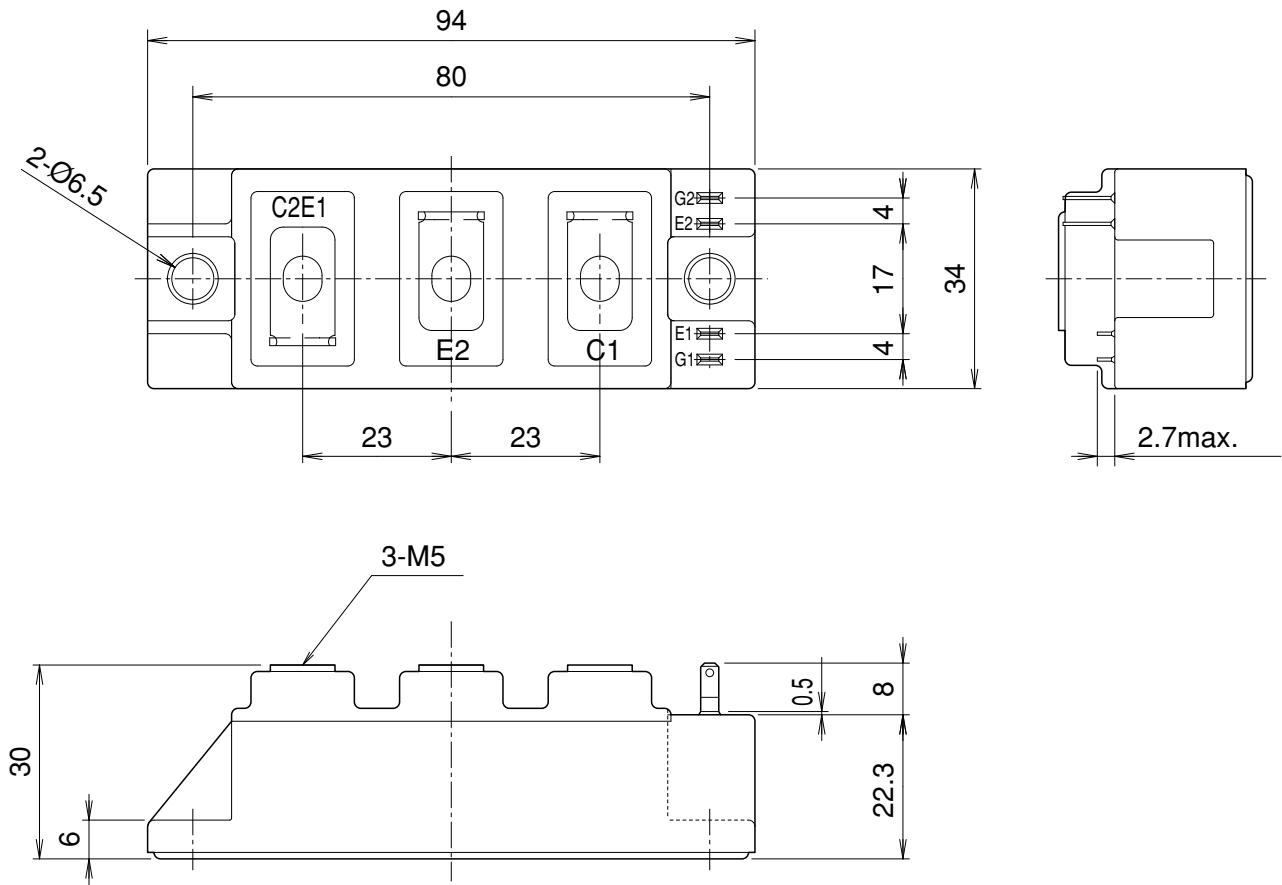


Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE} \le 15V, R_G \ge 9.1\Omega, T_j \le 125^\circ C$

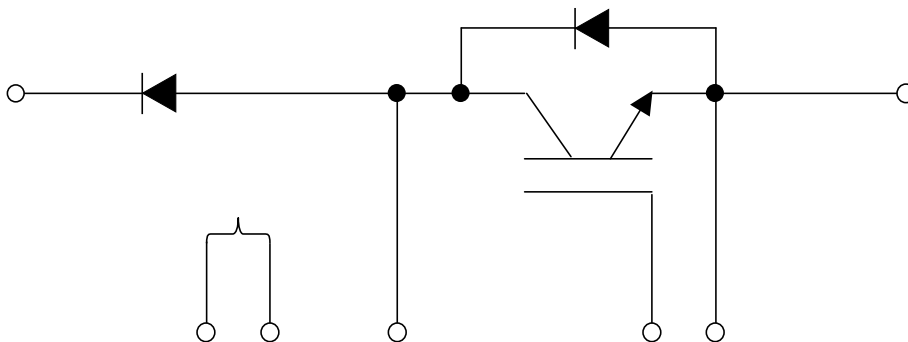




■ Outline Drawings, mm



■ Equivalent Circuit Schematic



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